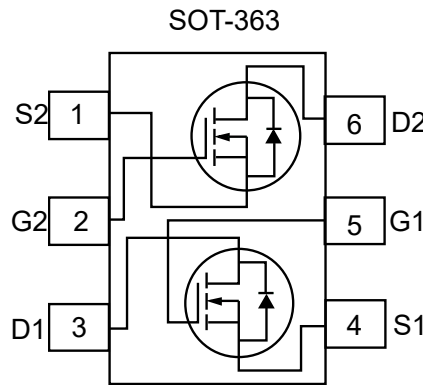


**Description**

The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

MOSFET Product Summary		
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)
20	0.29@ V <sub>GS</sub> =4.5V	0.5



**Absolute maximum rating@25°C**

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V <sub>DS</sub>	20	V
Gate-Source Voltage	V <sub>GS</sub>	8	V
Continuous Drain Current (T <sub>J</sub> =150°C)	I <sub>D</sub>	Continuous	0.5
		Pulsed	1.5
Maximum Power Dissipation	P <sub>D</sub>	0.3	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C
<b>Thermal Characteristics</b>			
Parameter	Symbol	Maximum	Units
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub>	415	°C/W

## Electrical characteristics per line@25°C ( unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	20		-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=8V$	-	-	10	$\mu A$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	-	1.1	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=0.5A$		0.29	0.34	$\Omega$
		$V_{GS}=2.7V, I_D=0.2A$		0.35	0.42	
On-State Drain Current	$I_{D(on)}$	$V_{GS}=2.7V, V_{DS}=5V$	0.5			A
Forward Trans conductance	$g_{FS}$	$V_{DS}=5V, I_D=0.5A$		1.45		S
Total Gate Charge	$Q_g$	$V_{GS}=4.5V, V_{DS}=5V, I_D=0.5A$		1.64	2.3	nC
Gate-Source Charge	$Q_{gs}$			0.38		
Gate-Drain Charge	$Q_{gd}$			0.45		
Input Capacitance	$C_{iss}$	$V_{GS}=0V, V_{DS}=10V, f=1MHz$	-	50		pF
Output Capacitance	$C_{oss}$		-	28		pF
Reverse Transfer Capacitance	$C_{rss}$		-	9		pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=5V, R_{GEN}=50\Omega, V_{GS}=4.5V, I_D=0.5A$	-	3	6	ns
Turn-Off Delay Time	$t_{d(off)}$		-	17	30	ns
Turn-On Rise Time	$t_r$		-	8.5	18	ns
Turn-On Fall Time	$t_f$		-	13	25	ns
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=0.25A$		0.8	1.2	V
Maximum Body-Diode Continuous Current	$I_S$				0.25	A

Typical Characteristics

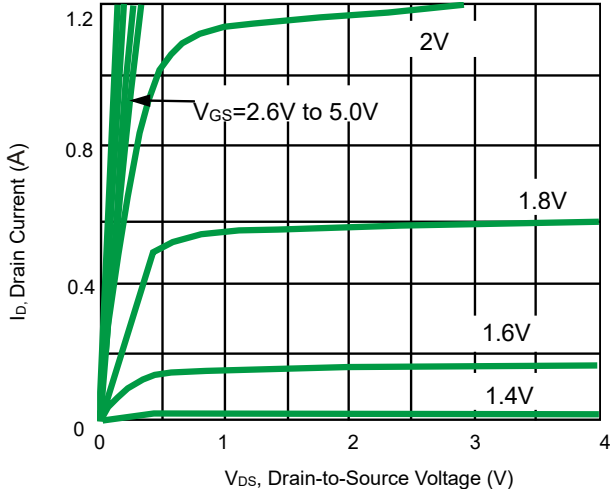


Fig 1. On-Region Characteristics

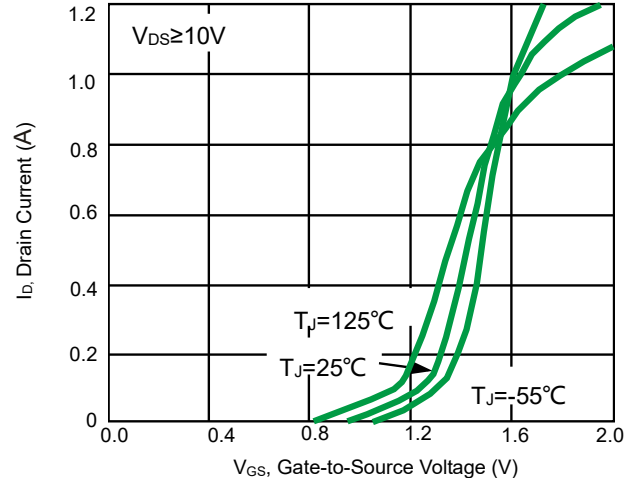


Fig 2. Transfer Characteristics

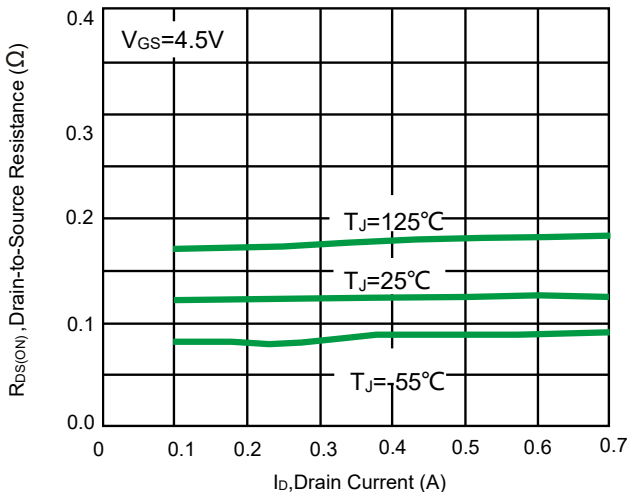


Fig 3. On-Resistance vs. Drain Current and Temperature

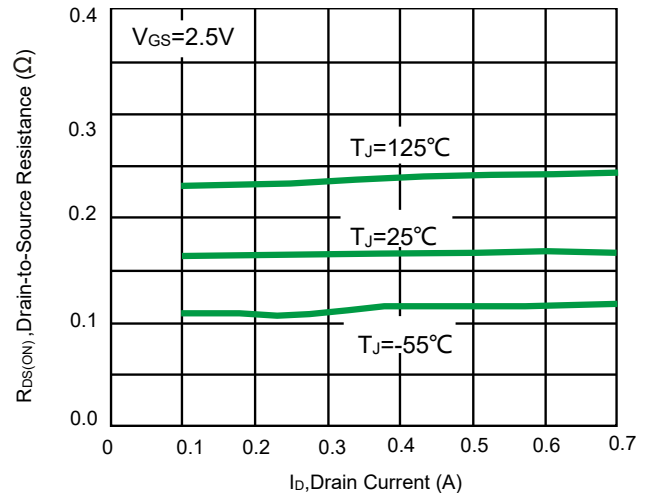


Fig 4. On-Resistance vs. Drain Current and Temperature

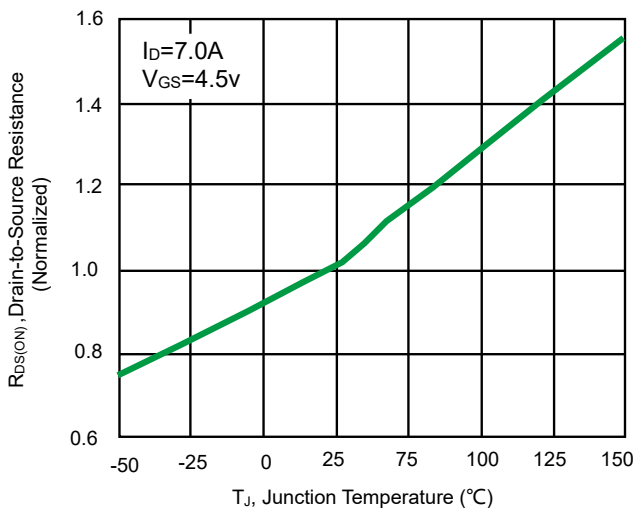


Fig 5. On-Resistance Variation with Temperature

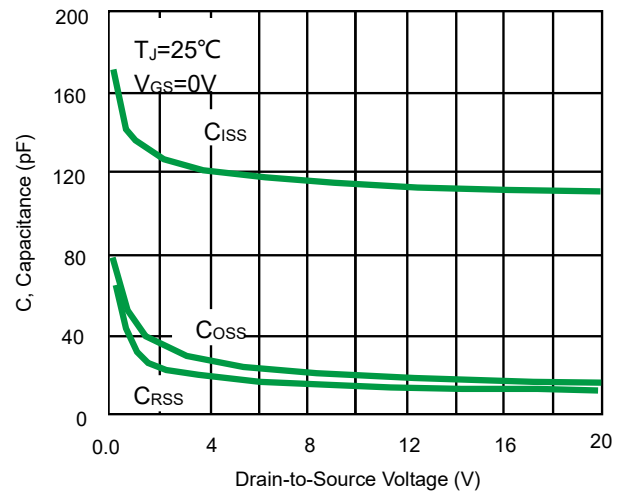


Fig 6. Characteristics Variation

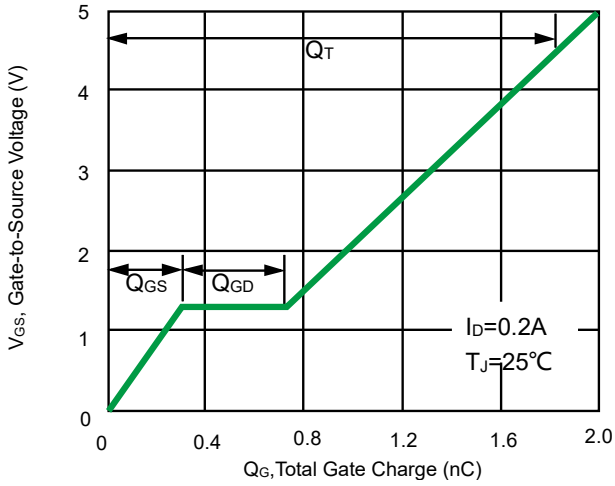


Fig 7. Gate-to-Source Voltage vs. Total Gate Charge

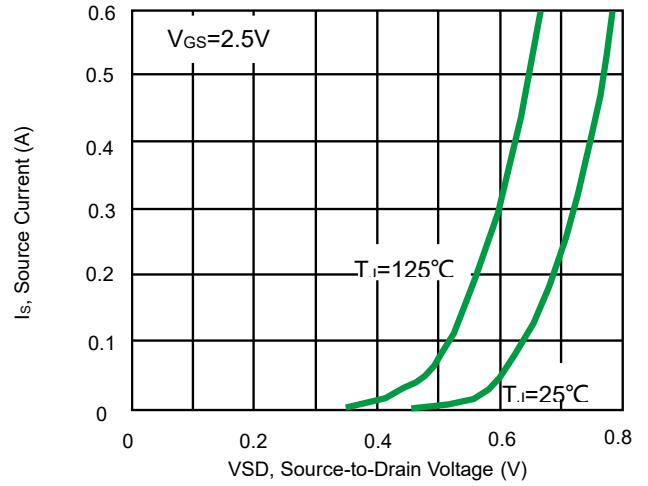


Fig 8. Diode Forward Voltage vs. Current

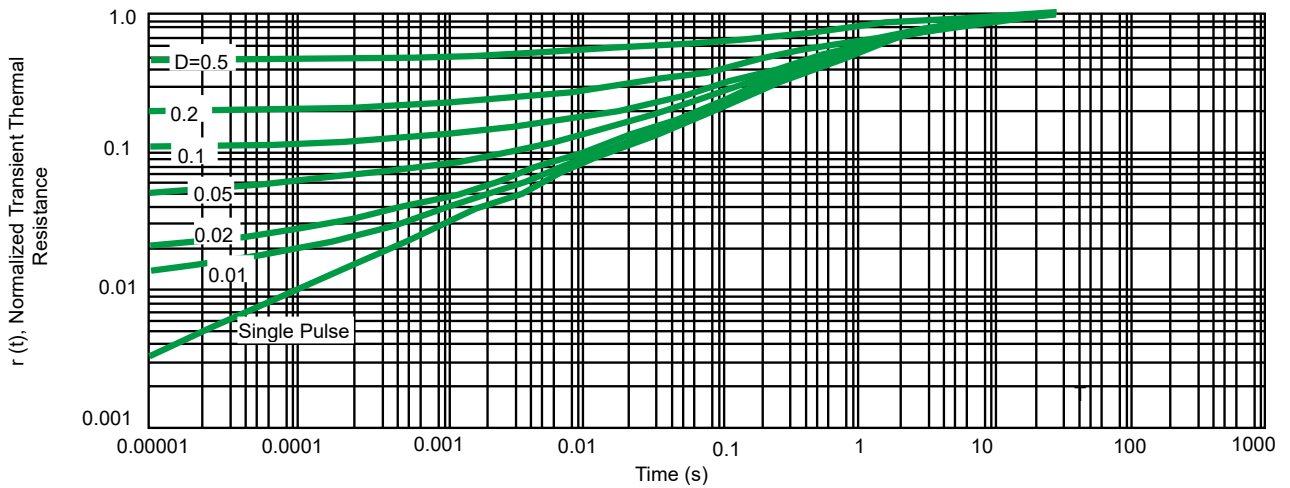
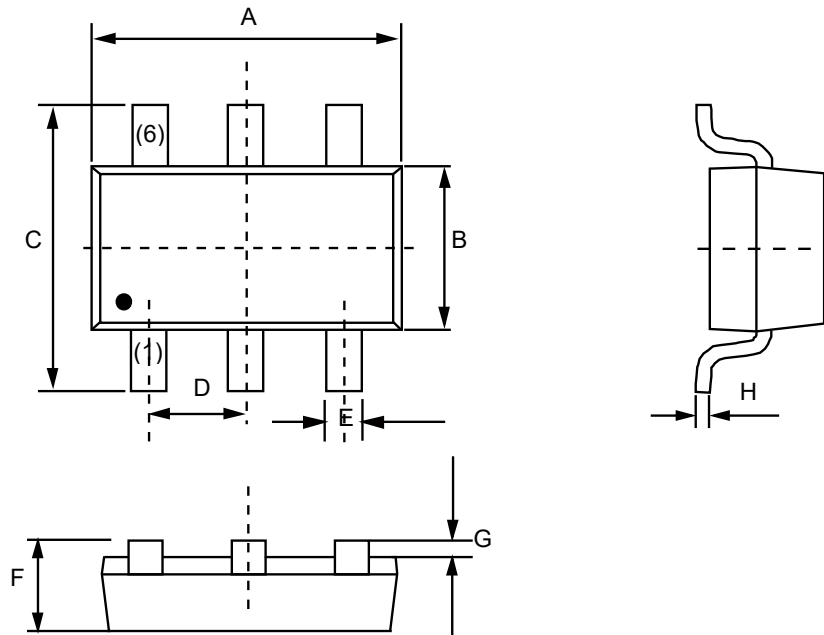


Fig 9. Normalized Thermal Response

## Product dimension (SOT-363)

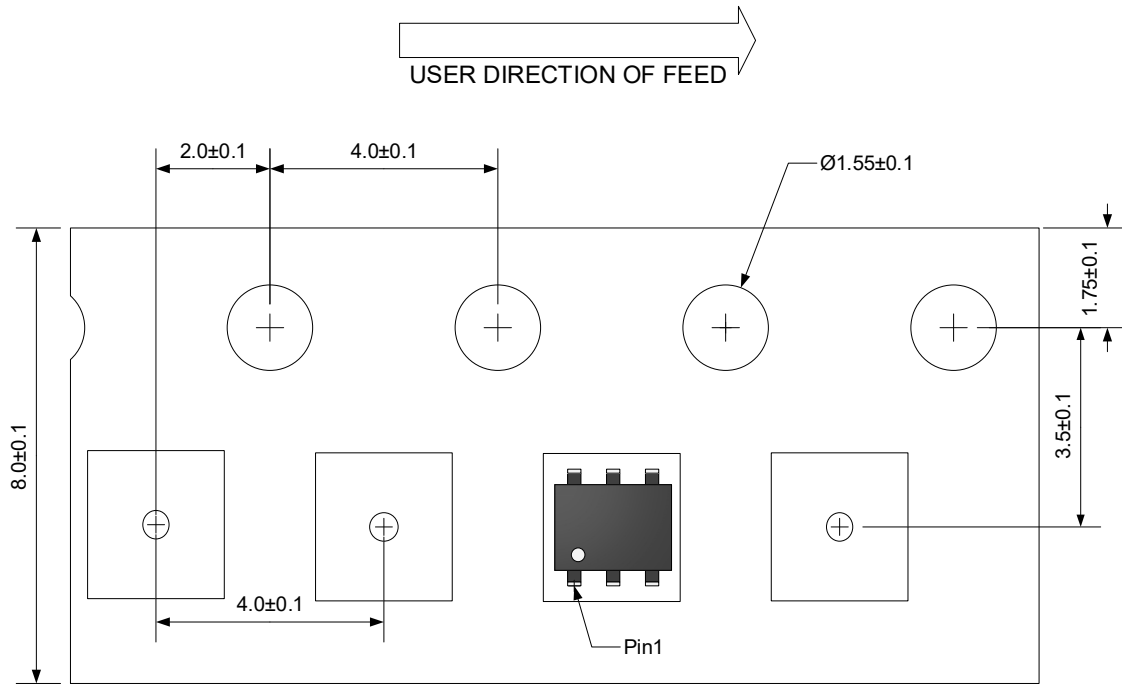


Dim	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	2.0	2.2	0.079	0.087
B	1.15	1.35	0.045	0.053
C	2.15	2.45	0.085	0.096
D	0.65BSC		0.026BSC	
E	0.15	0.35	0.006	0.014
F	0.90	1.10	0.035	0.043
G	0.00	0.10	0.000	0.004
H	0.08	0.15	0.003	0.006

## Ordering information

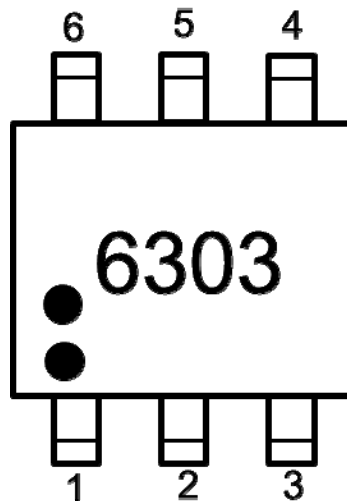
Device	Package	Shipping
PDNM6UT20V05	SOT-363 (Pb-Free)	3000 / Tape & Reel

Load With Information




Unit:mm

Marking Information




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